



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of: **Mitsushi FUJIKI**

Group Art Unit: **2823**

Application Number: **10/772,253**

Examiner: **Thanh V. Pham**

Filed: **February 6, 2004**

Confirmation Number: **6491**

For: **METHOD OF MANUFACTURING SEMICONDUCTOR DEVICE  
INCLUDING A LOW-TEMPERATURE LOWER ELECTRODE-  
FORMING STEP**

Attorney Docket Number: **042068**

Customer Number: **38834**

**INFORMATION DISCLOSURE STATEMENT**  
**UNDER 37 C.F.R. §1.97(c)(1)/(e)(1)**

Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

October 10, 2007

Sir:

Applicants direct the attention of the Patent and Trademark Office to the documents listed on the attached Form PTO/SB/08. A copy of each non - U.S. document is attached.

This Information Disclosure Statement (IDS) is being submitted after issuance of a first official action on the merits and expiration of the three month period following the filing date or the entry of the national stage for the above-captioned application, but prior to issuance of either a final official action or a Notice of Allowance.

The undersigned hereby certifies that each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the IDS. A copy of the foreign communication citing the documents is attached.

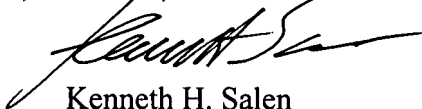
Information Disclosure Statement under 1.97(c)(1)  
Attorney Docket No. 042068  
Application No. 10/772,253

Each listed document was first cited in a communication from a foreign patent office and the communication was not received by any person defined in 37 C.F.R. §1.56(c) more than 30 days before filing of this paper.

If there are any fees due in connection with the filing of this paper, please charge Deposit Account No. 50-2866.

Respectfully submitted,

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Enclosures: PTO/SB/08  
5 Documents